

Vishay Siliconix

Dual P-Channel 30-V (D-S) MOSFET

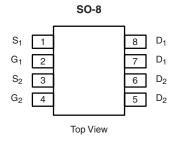
PRODUCT SUMMARY					
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)			
- 30	0.025 at V _{GS} = - 10 V	- 7.1			
	0.041 at V _{GS} = - 4.5 V	- 5.5			

FEATURES

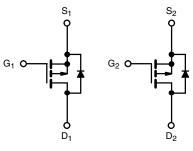
- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFET
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Load Switches
 - Notebook PCs
 - Desktop PCs
 - Game Stations



Ordering Information: Si4925BDY-T1-E3 (Lead (Pb)-free) Si4925BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_A = 25 \text{ °C}$, unless otherwise noted							
Parameter		Symbol	10 s	Steady State	Unit		
Drain-Source Voltage		V _{DS}	- 30		v		
Gate-Source Voltage		V _{GS}	± 20				
	T _A = 25 °C	- I _D -	- 7.1	- 5.3			
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 5.7	- 4.3	٨		
Pulsed Drain Current		I _{DM}	- 40		A		
Continuous Source Current (Diode Conduction) ^a		۱ _S	- 1.7	- 0.9			
	T _A = 25 °C	P	2.0	1.1	W		
Maximum Power Dissipation ^a	T _A = 70 °C	P _D	1.3	0.7	VV		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C		

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Typical	Maximum	Unit		
NA	t ≤ 10 s	R _{thJA}	50	62.5		
Maximum Junction-to-Ambient ^a	Steady State		85	110	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	30	40		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.



FREE

Available

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noted					
Test Conditions	Min.	Тур.	Max.	Unit	
= V _{GS} , I _D = - 250 μA	- 1		- 3	V	
$_{\rm S}$ = 0 V, V _{GS} = ± 20 V			± 100	nA	
_S = - 30 V, V _{GS} = 0 V			- 1	μΑ	
0 V, V _{GS} = 0 V, T _J = 55 °C			- 25		

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 1		- 3	۷	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zaus Cata Valtana Dusia Cuurant		$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 1		
Zero Gate Voltage Drain Current	IDSS	V_{DS} = - 30 V, V_{GS} = 0 V, T_{J} = 55 °C			- 25	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 V, V_{GS} = -10 V$	- 40			А	
	Б	V _{GS} = - 10 V, I _D = - 7.1 A		0.020	0.025		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 5.5 A		0.033	0.041	Ω	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 7.1 A		20		S	
Diode Forward Voltage ^a	V _{SD}	I _S = - 1.7 A, V _{GS} = 0 V		- 0.8	- 1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			33	50		
Gate-Source Charge	Q _{gs}	V_{DS} = - 15 V, V_{GS} = - 10 V, I_{D} = - 7.1 A		5.4		nC	
Gate-Drain Charge	Q _{gd}			8.9			
Turn-On Delay Time	t _{d(on)}			9	15		
Rise Time	t _r	V_{DD} = - 15 V, R_L = 15 Ω		12	20	ns	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ - 1 A, V_GEN = - 10 V, R_g = 6 Ω		60	90		
Fall Time	t _f			34	50		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.7 A, dl/dt = 100 A/μs	I _F = - 1.7 A, dl/dt = 100 A/μs 30		60	1	

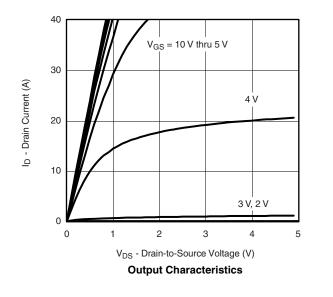
Notes:

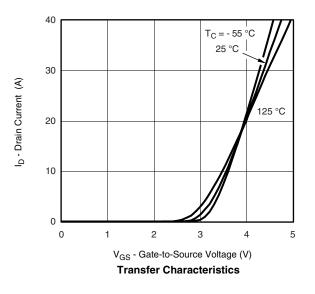
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



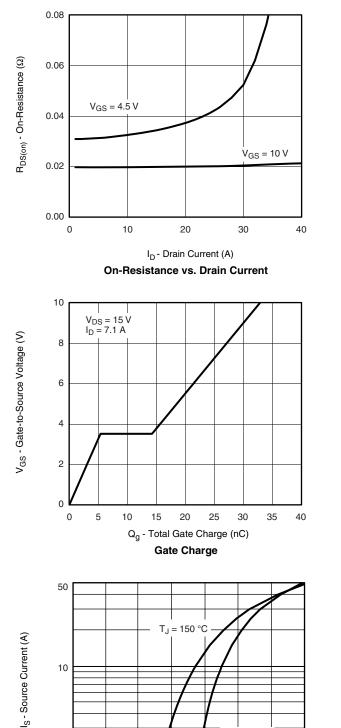




Si4925BDY

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

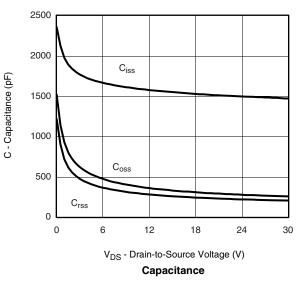


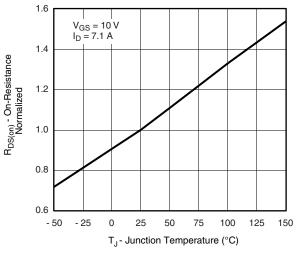
T_J = 25 °C

1.0

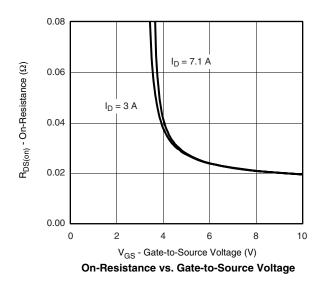
1.2

1.4





On-Resistance vs. Junction Temperature



1 L

0.2

0.4

0.6

V_{SD} - Source-to-Drain Voltage (V)

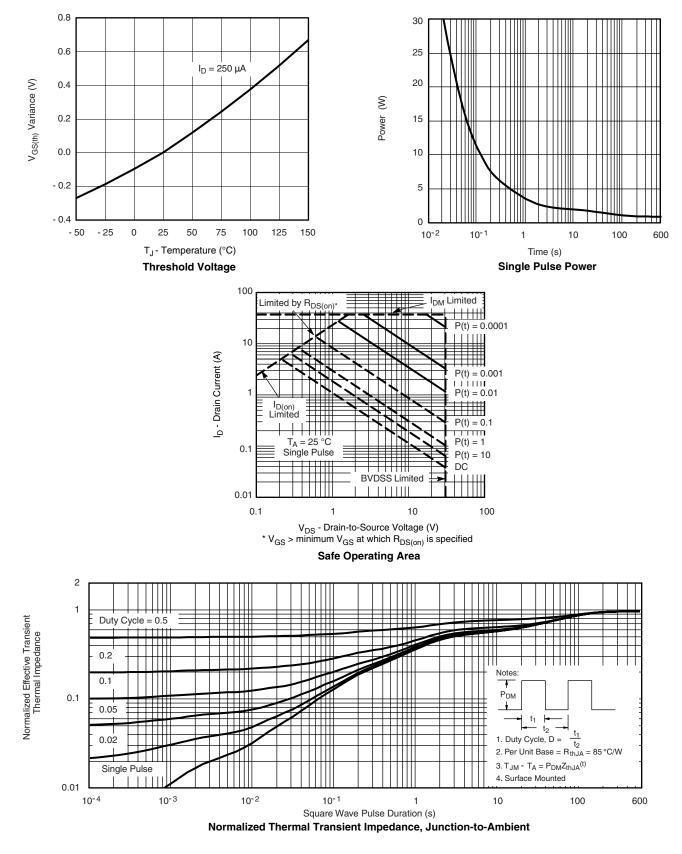
Source-Drain Diode Forward Voltage

0.8

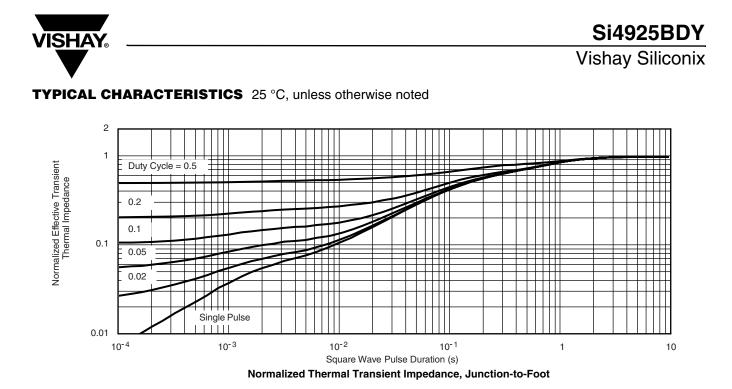
Si4925BDY

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Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg772001.



Package Information

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SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





	MILLIM	IETERS	INC	HES		
DIM	Min	Мах	Min	Max		
A	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498						

Application Note 826

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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